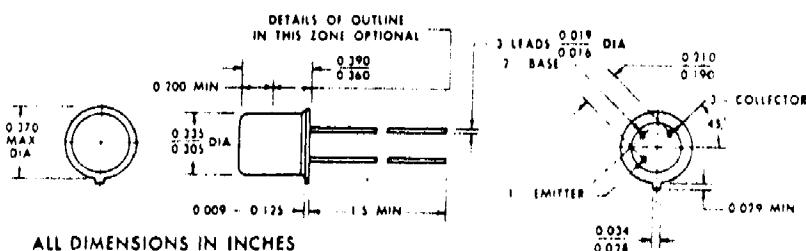


# New Jersey Semi-Conductor Products, Inc.

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## TYPES 2N339, 2N340, 2N341, 2N342, 2N342A, 2N343 N-P-N GROWN SILICON TRANSISTORS



### Absolute maximum ratings at 25°C case temperature (unless otherwise noted)

*Collector Current	60 mA
*Total Device Dissipation (see note 1)	1000 mW
*Total Device Dissipation at 100°C Case Temperature (see note 1)	400 mW
*Total Device Dissipation at 125°C Case Temperature (see note 1)	200 mW
*Storage and Operating Collector Junction Temperature Range	-65° to +150°C
Storage and Operating Collector Junction Temperature (TI Guarantee)	-65° to +175°C

### Electrical characteristics at 25°C case temperature (unless otherwise noted)

parameter	test conditions	2N339		2N340		2N341		2N342		2N342A		2N343		unit
		min	max											
I <sub>CEO</sub>	Collector Cutoff Current V <sub>CE</sub> = 30 v I <sub>E</sub> = 0	1		1		1		1		1		1		μA
I <sub>CEO</sub>	Collector Cutoff Current V <sub>CE</sub> = 30 v I <sub>E</sub> = 0 T <sub>C</sub> = +150°C	250		250		250		250		250		250		μA
V <sub>BCBO</sub>	Collector-Base Breakdown Voltage I <sub>C</sub> = 50 μA I <sub>E</sub> = 0	55		85		125		60		85		60		v
V <sub>BEBO</sub>	Collector-Emitter Breakdown Voltage I <sub>C</sub> = 100 μA I <sub>E</sub> = 0	55		85		85		60		85		60		v
V <sub>BEBO</sub>	Emitter-Base Breakdown Voltage I <sub>E</sub> = 100 μA I <sub>C</sub> = 0	1		1		1		1		1		1		v
R <sub>CE(sat)</sub>	DC Collector-Emitter Saturation Resistance I <sub>E</sub> = 3 mA I <sub>C</sub> = 20 mA	300		350		400		350		350		350		ohm
H <sub>fb</sub>	AC Common-Base Forward Current Transfer Ratio V <sub>CE</sub> = 10 v I <sub>E</sub> = -5 mA I = 1 kΩ	-0.989	-0.9	-0.989	-0.9	-0.989	-0.9	-0.97	-0.9	-0.97	-0.9	-0.966	-0.989	-
H <sub>ib</sub>	AC Common-Base Input Impedance V <sub>CE</sub> = 10 v I <sub>E</sub> = -5 mA I = 1 kΩ	30		30		30		30		30		30		30 ohm
H <sub>ob</sub>	AC Common Base Output Admittance V <sub>CE</sub> = 10 v I <sub>E</sub> = -5 mA I = 1 kΩ	2		2		2		2		2		2		2 μmho
H <sub>rb</sub>	AC Common Base Reverse Voltage Transfer Ratio V <sub>CE</sub> = 10 v I <sub>E</sub> = -5 mA I = 1 kΩ	300 x10 <sup>-6</sup>		-										

NJ Semi-Conductors reserves the right to change test conditions, parameter limits and package dimensions without notice. Information furnished by NJ Semi-Conductors is believed to be both accurate and reliable at the time of going to press. However NJ Semi-Conductors assumes no responsibility for any errors or omissions discovered in its use. NJ Semi-Conductors encourages customers to verify that datasheets are current before placing orders.

